NCP1410

250 mA Sync-Rect PFM Step-Up DC-DC Converter with Low-Battery Detector

NCP1410 is a monolithic micropower high frequency Boost (step–up) voltage switching converter IC specially designed for battery operated hand–held electronic products up to 250 mA loading. It integrates Synchronous Rectifier for improving efficiency as well as eliminating the external Schottky Diode. High switching frequency (up to 600 kHz) allows low profile inductor and output capacitor being used. Low–Battery Detector, Logic–Controlled Shutdown and Cycle–by–Cycle Current Limit provide value–added features for various battery–operated applications. With all these functions ON, the device quiescent supply current is only 9.0 μA typical. This device is available in space saving compact Micro8™ package.

Features

- High Efficiency up to 92%
- Very Low Device Quiescent Supply Current of 9.0 μA Typical
- Allows use of Small Size Inductor and Capacitor
- Built–in Synchronous Rectifier (PFET) Eliminates One External Schottky Diode
- High Switching Frequency (up to 600 kHz) Allows Use of Small Size Inductor and Capacitor
- High Accuracy Reference Output, 1.19 V ± 0.6% @ 25°C, can supply more than 2.5 mA when $V_{OUT} \geq 3.3$ V
- 1.0 V Startup at No Load Guaranteed
- Output Voltage from 1.5 V to 5.5 V Adjustable
- Output Current up to 250 mA @ V_{in} = 2.5 V, V_{out} = 3.3 V
- Logic–Controlled Shutdown
- Open Drain Low–Battery Detector Output
- 1.0 A Cycle–by–Cycle Current Limit
- Low Profile and Minimum External Parts
- Compact Micro8 Package
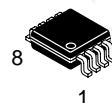- Pb–Free Package is Available

Typical Applications

- Personal Digital Assistant (PDA)
- Handheld Digital Audio Product
- Camcorders and Digital Still Camera
- Hand–held Instrument
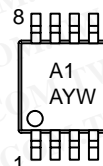- Conversion from One or Two NiMH or NiCd, or One Li–ion Cell to 3.3 V/5.0 V
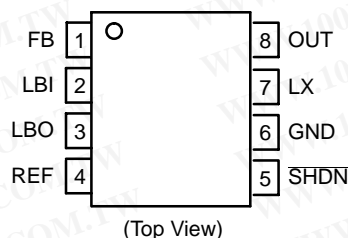
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MARKING DIAGRAM

Micro8™
DM SUFFIX
CASE 846A

A1
AYW

A1 = Device Marking
A = Assembly Location
Y = Year
W = Work Week

PIN CONNECTIONS

FB	1	8 OUT
LBI	2	7 LX
LBO	3	6 GND
REF	4	5 SHDN

(Top View)

ORDERING INFORMATION

Device	Package	Shipping[†]
NCP1410DMR2	Micro8	4000 Tape & Reel
NCP1410DMR2G	Micro8 (Pb–Free)	4000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NCP1410
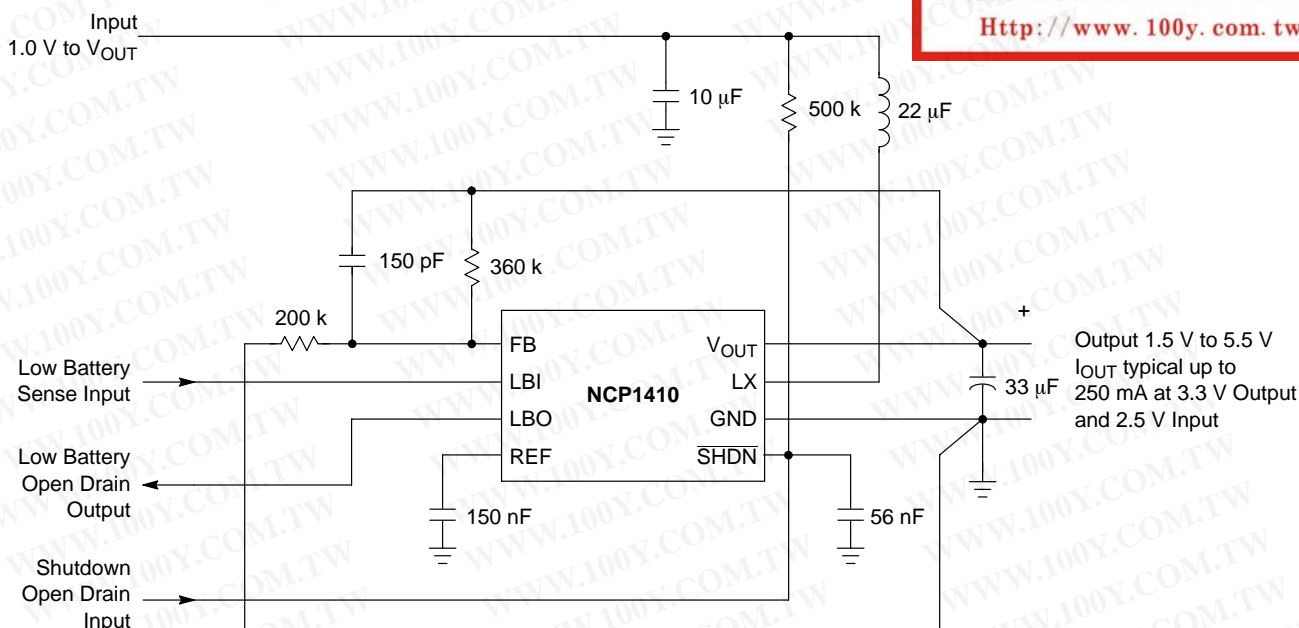
Figure 1. Typical Operating Circuit

MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Device Power Supply (Pin 8)	V_{OUT}	−0.3 to 6.0	V
Input/Output Pins (Pin 1−5, Pin 7)	V_{IO}	−0.3 to 6.0	V

Thermal Characteristics − Micro8 Plastic Package
  Maximum Power Dissipation @ T_A = 25°C
  Thermal Resistance Junction to Air
	P_D
	$R_{\theta JA}$
		520
		240
			mW
			°C/W

Operating Junction Temperature Range	T_J	−40 to +150	°C
Operating Ambient Temperature Range	T_A	−40 to +85	°C
Storage Temperature Range	T_{stg}	−55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. This device series contains ESD protection and exceeds the following tests:
    Human Body Model (HBM) ±2.0 kV per JEDEC standard: JESD22−A114.
    Machine Model Method (MM) ±200 V per JEDEC standard: JESD22−A115.
2. The maximum package power dissipation limit must not be exceeded.

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

3. Latchup Current Maximum Rating: ±150 mA per JEDEC standard: JESD78.
4. Moisture Sensitivity Level: MSL 1 per IPC/JEDEC standard: J−STD−020A.

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Characteristics	Symbol	Min	Typ	Max	Unit
Operating Voltage	V_{IN}	1.0	–	5.5	V
Output Voltage Range (Adjusted by external feedback)	V_{OUT}	V_{IN}	–	5.5	V
Reference Voltage (C_{REF} = 150 nF, under no loading, T_A = 25°C)	V_{REF_NL}	1.183	1.190	1.197	V
Reference Voltage (C_{REF} = 150 nF, under no loading, −40°C ≤ T_A ≤ 85°C)	$V_{REF\_NL\_A}$	1.178	–	1.202	V
Reference Voltage Temperature Coefficient	TC_{VREF}	–	0.03	–	mV/°C
Reference Voltage Load Current (V_{OUT} = 3.3 V, V_{REF} = V_{REF_NL} ±1.5%, C_{REF} = 1.0 μF) (Note 5)	I_{REF}	2.5	–	–	mA
Reference Voltage Load Regulation (V_{OUT} = 3.3 V, I_{REF} = 0 to 100 μA, C_{REF} = 1.0 μF)	V_{REF_LOAD}	–	0.015	1.0	mV
Reference Voltage Line Regulation (V_{OUT} from 1.5 V to 5.5 V, C_{REF} = 1.0 μF)	V_{REF_LINE}	–	0.03	1.0	mV/V
FB, LBI Input Threshold (I_{LOAD} = 0 mA)	V_{FB}, V_{LBI}	1.174	1.190	1.200	V
N–FET ON Resistance	$R_{DS(ON)-N}$		0.6		Ω
P–FET ON Resistance	$R_{DS(ON)-P}$		0.9		Ω
LX Switch Current Limit (NFET)	I_{LIM}	–	1.0	–	A
Operating Current into OUT (V_{FB} = 1.4 V, i.e. No switching, V_{OUT} = 3.3 V)	I_Q	–	9.0	14	μA
Shutdown Current into OUT ($\overline{SHDN}$ = GND)	I_{SD}	–	0.05	1.0	μA
LX Switch MAX. ON–Time (V_{FB} = 1.0 V, V_{OUT} = 3.3 V)	t_{ON}	1.2	1.4	1.8	μS
LX Switch MIN. OFF–Time (V_{FB} = 1.0 V, V_{OUT} = 3.3 V)	t_{OFF}	0.25	0.31	0.37	μS
FB Input Current	I_{FB}	–	1.5	9.0	nA
LBI Input Current	I_{LBI}	–	1.5	8.0	nA
LBO Low Output Voltage (V_{LBI} = 0, I_{SINK} = 1.0 mA)	V_{LBO_L}	–	–	0.05	V
$\overline{SHDN}$ Input Current	I_{SHDN}	–	1.5	8.0	nA
$\overline{SHDN}$ Input Threshold, Low	V_{SHDN_L}	–	–	0.3	V
$\overline{SHDN}$ Input Threshold, High	V_{SHDN_H}	0.6	–	–	V

5. Loading capability increases with V_{OUT}.

PIN FUNCTION DESCRIPTIONS

Pin #	Symbol	Pin Description
1	FB	Output Voltage Feedback Input.
2	LBI	Low–Battery Detector Input.
3	LBO	Open–Drain Low–Battery Detector Output. Output is LOW when V_{LBI} is < 1.178 V. LBO is high impedance during shutdown.
4	REF	1.190 V Reference Voltage Output, bypass with 150 nF capacitor if this pin is not loaded, bypass with 1.0 μF if this pin is loaded up to 2.5 mA @ V_{OUT} = 3.3 V.
5	$\overline{SHDN}$	Shutdown Input. HIGH (> 0.6 V) = operating; LOW (< 0.3 V) = shutdown.
6	GND	Ground.
7	LX	N–Channel and P–Channel Power MOSFET Drain Connection.
8	OUT	Power Output. OUT provides bootstrap power to the IC.

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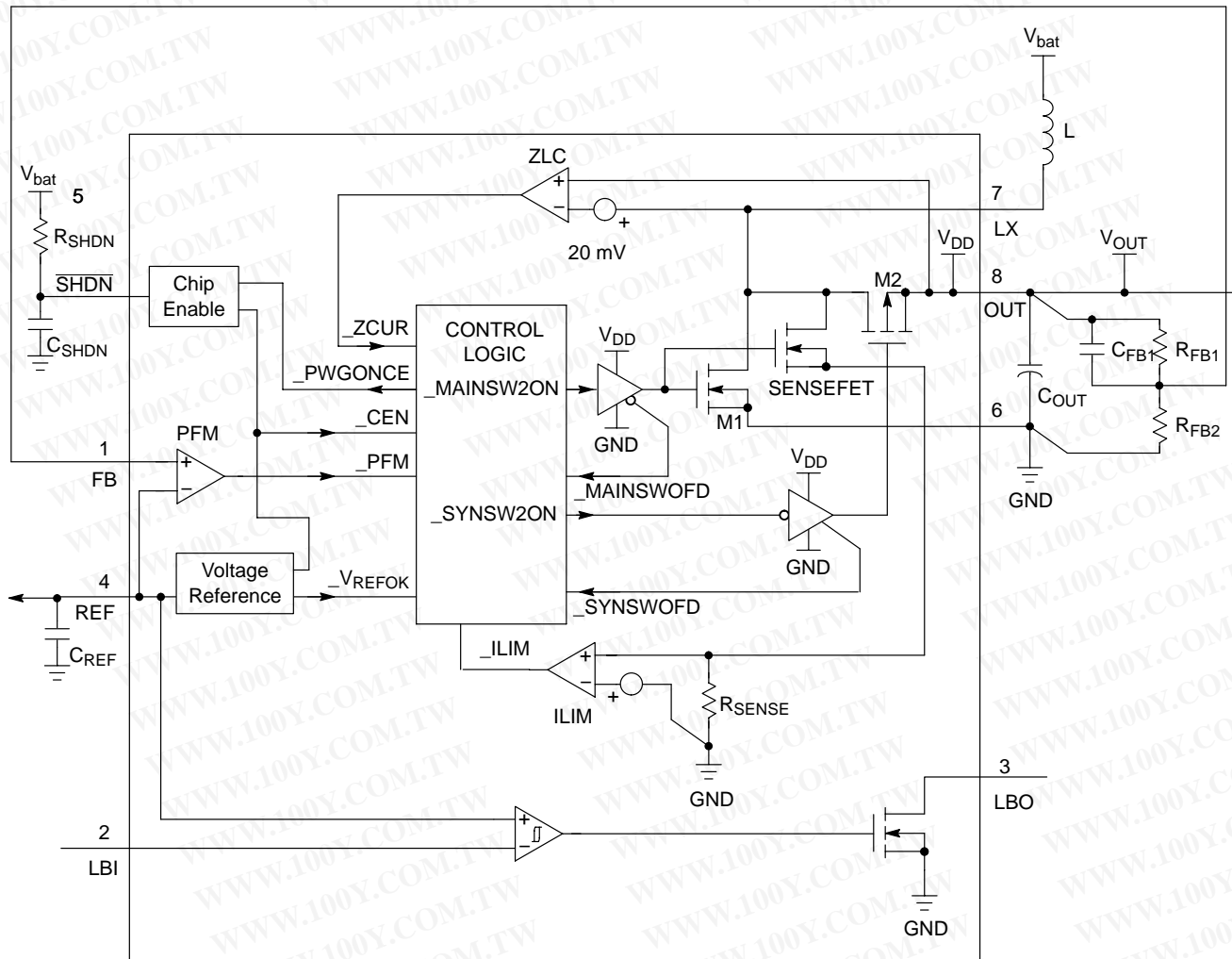胜特力电子(深圳) 86-755-83298787
Http://www.100y.com.tw

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Figure 2. Simplified Functional Diagram

TYPICAL OPERATING CHARACTERISTICS

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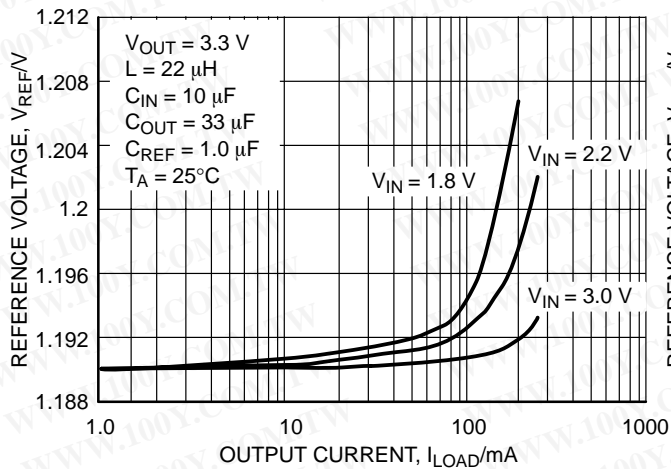胜特力电子(深圳) 86-755-83298787
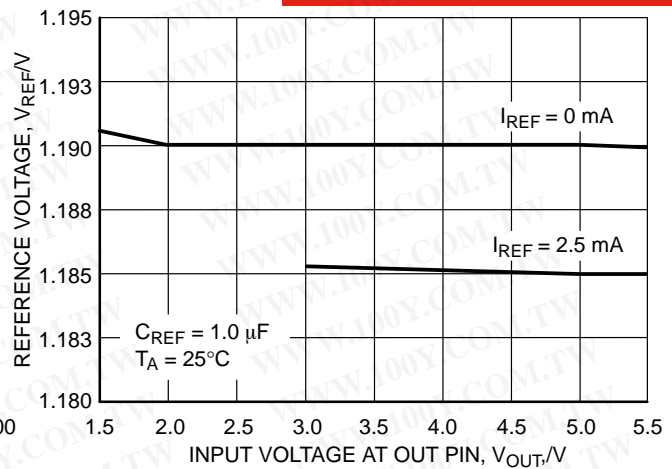Http://www.100y.com.tw

Figure 3. Reference Voltage vs. Output Current
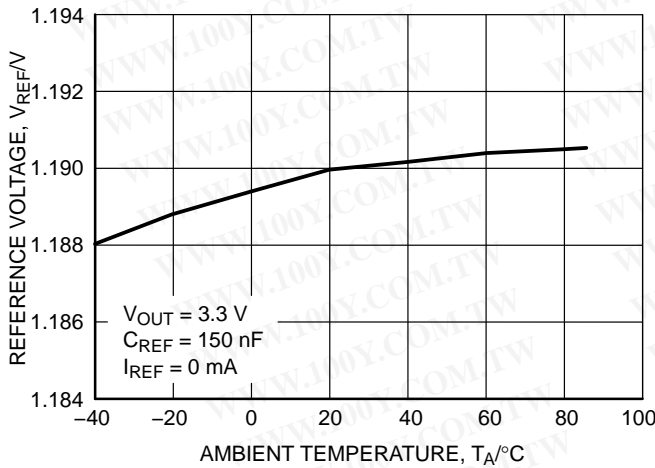

Figure 4. Reference Voltage vs. Input Voltage at OUT pin
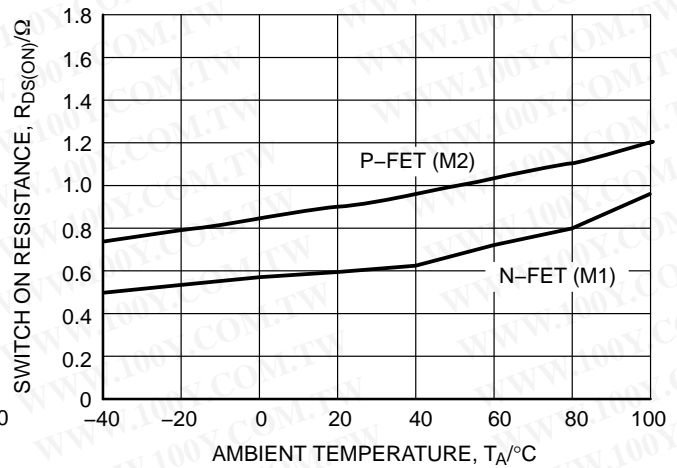

Figure 5. Reference Voltage vs. Temperature
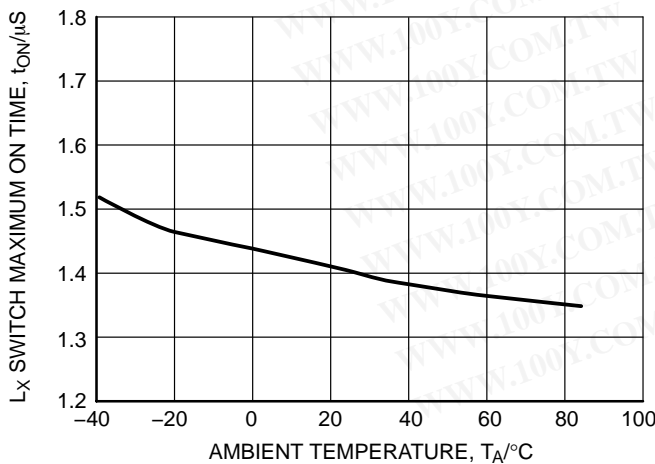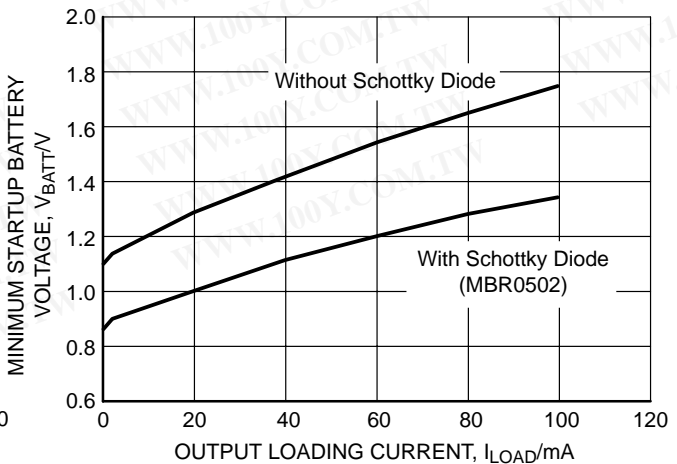

Figure 6. Switch ON Resistance vs. Temperature

Figure 7. L_X Switch Maximum ON Time vs. Temperature

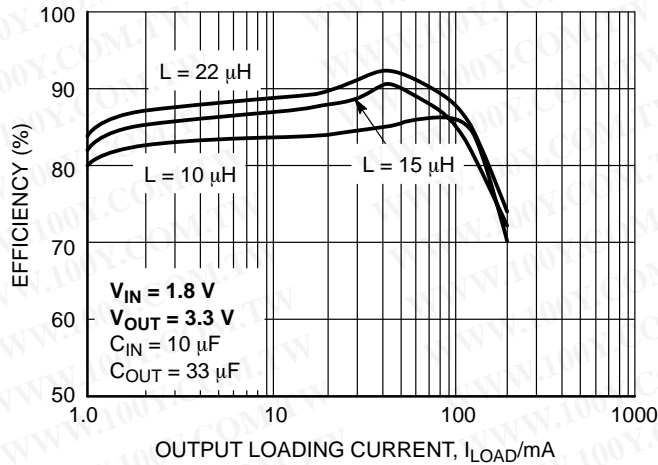Figure 8. Minimum Startup Battery Voltage vs. Loading Current

NCP1410

TYPICAL OPERATING CHARACTERISTICS

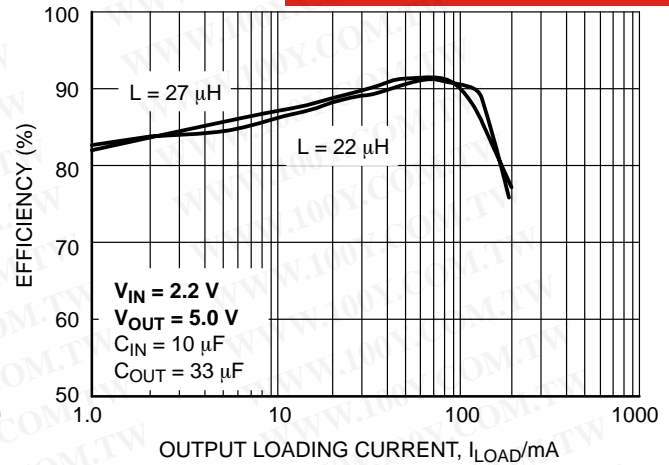**Figure 9. Efficiency vs. Load Current**
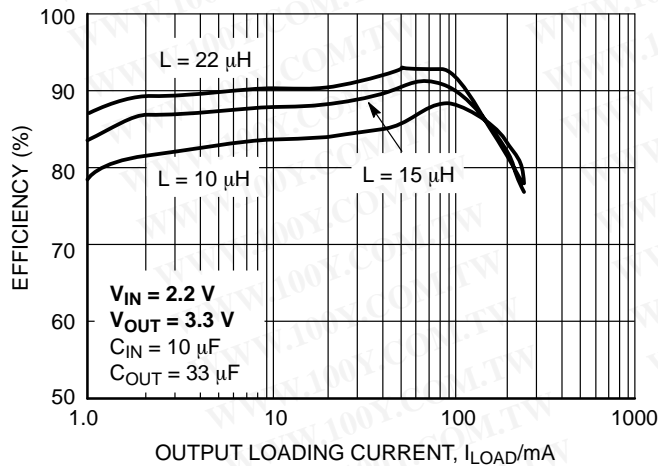

Figure 10. Efficiency vs. Load Current

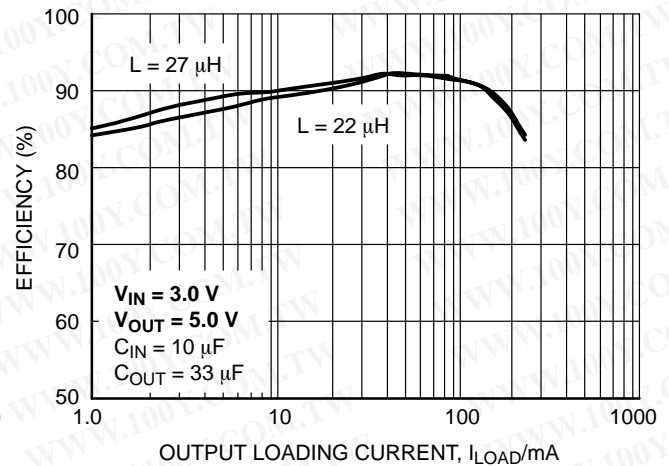**Figure 11. Efficiency vs. Load Current**

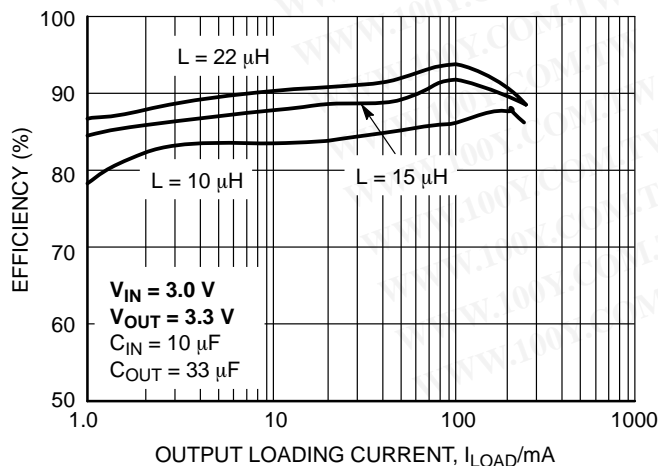**Figure 12. Efficiency vs. Load Current**
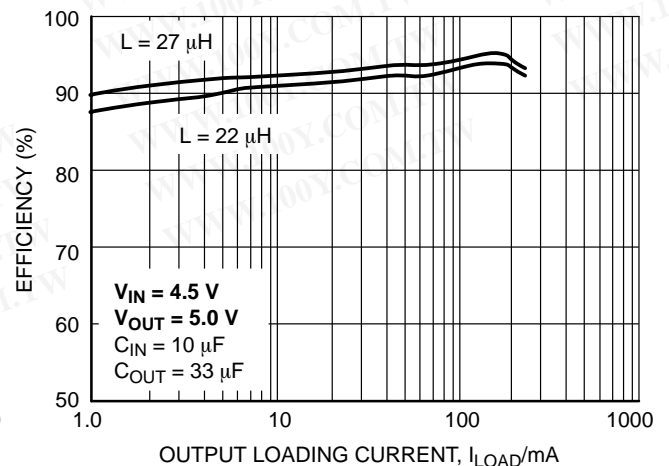

Figure 13. Efficiency vs. Load Current

Figure 14. Efficiency vs. Load Current
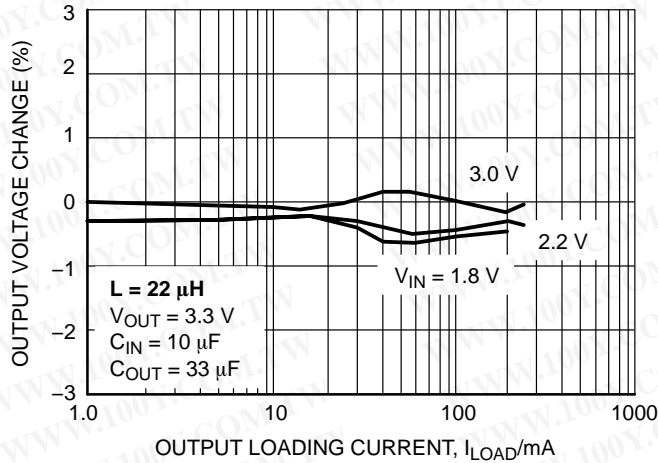
TYPICAL OPERATING CHARACTERISTICS

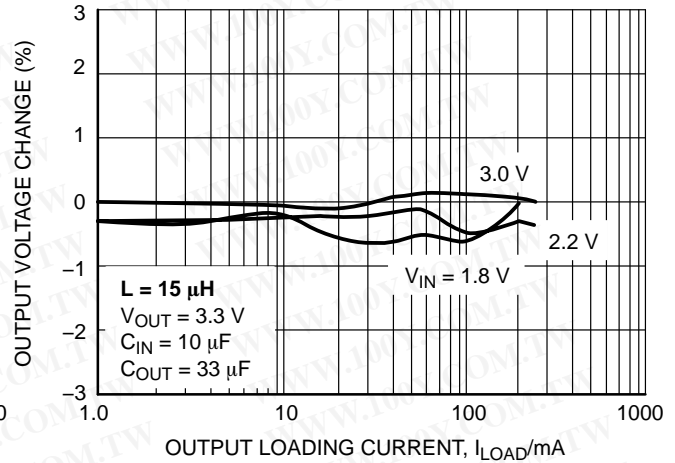**Figure 15. Output Voltage Change vs. Load Current**

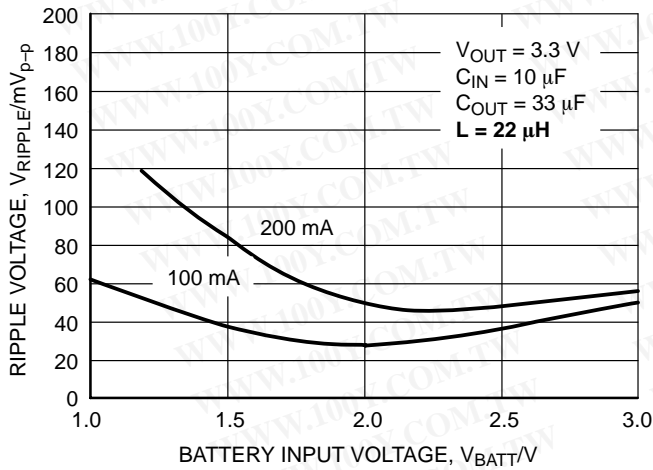**Figure 16. Output Voltage Change vs. Load Current**

Figure 17. Output Ripple Voltage vs. Battery Input Voltage

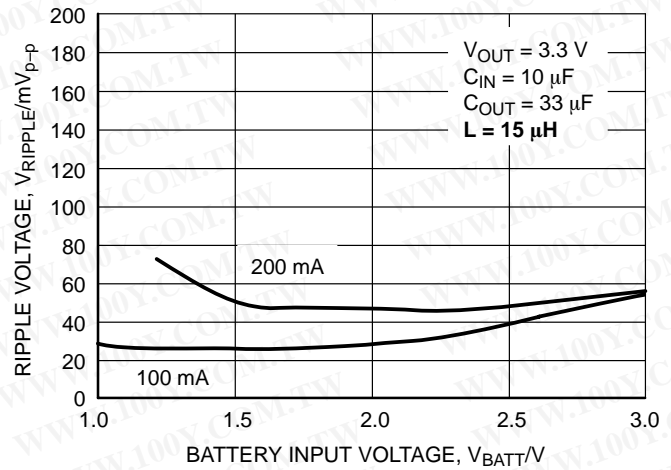**Figure 18. Output Ripple Voltage vs. Battery Input Voltage**
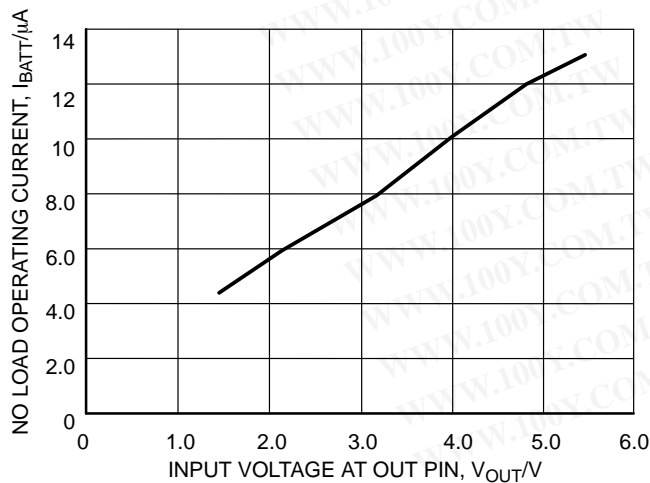
Figure 19. No Load Operating Current vs. Input Voltage at OUT Pin
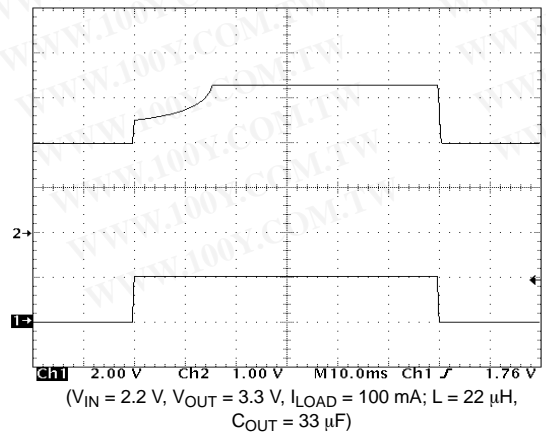
$(V_{IN} = 2.2 \text{ V}, V_{OUT} = 3.3 \text{ V}, I_{LOAD} = 100 \text{ mA}; L = 22 \text{ µH}, C_{OUT} = 33 \text{ µF})$
Upper Trace: Output Voltage Waveform, 2.0 V/Division
Lower Trace: Shutdown Pin Waveform, 1.0 V/Division

Figure 20. Startup Transient Response

TYPICAL OPERATING CHARACTERISTICS
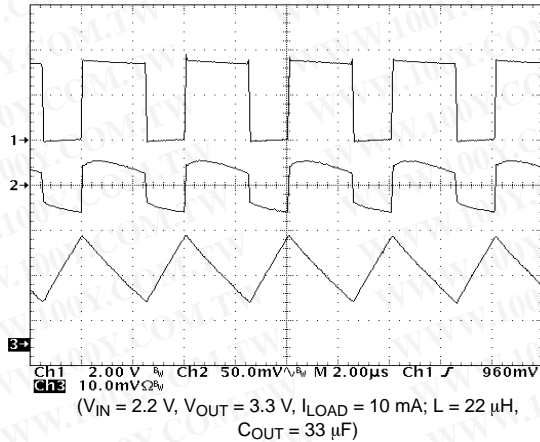
(V_{IN} = 2.2 V, V_{OUT} = 3.3 V, I_{LOAD} = 10 mA; L = 22 µH,
C_{OUT} = 33 µF)
Upper Trace: Voltage at L_X pin, 2.0 V/Division
MiddleTrace Otuput Voltage Ripple, 50 mV/Division
Lower Trace: Inductor Current, I_L, 100 mA/Division

**Figure 21. Continuous Conduction Mode
Switching Waveform**
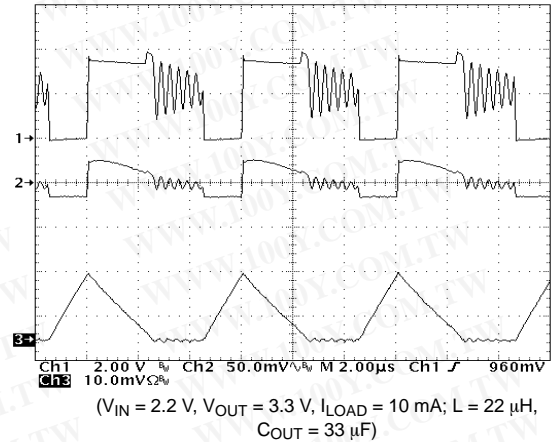
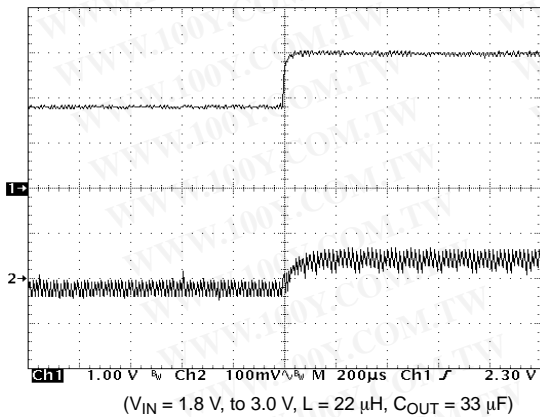(V_{IN} = 2.2 V, V_{OUT} = 3.3 V, I_{LOAD} = 10 mA; L = 22 µH,
C_{OUT} = 33 µF)
Upper Trace: Voltage at L_X pin, 2.0 V/Division
MiddleTrace Otuput Voltage Ripple, 50 mV/Division
Lower Trace: Inductor Current, I_L, 100 mA/Division

**Figure 22. Discontinuous Conduction Mode
Switching Waveform**

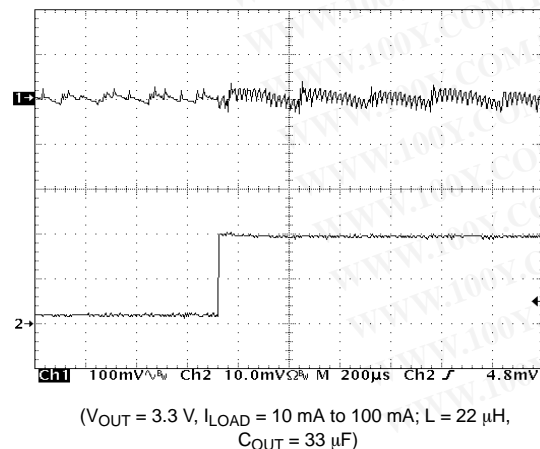(V_{IN} = 1.8 V, to 3.0 V, L = 22 µH, C_{OUT} = 33 µF)
Upper Trace: Battery Voltage, V_{IN}, 1.0 V/Division
Lower Trace: Output Voltage Ripple, 100 mV/Division

Figure 23. Line Transient Response for V_{OUT} = 3.3 V
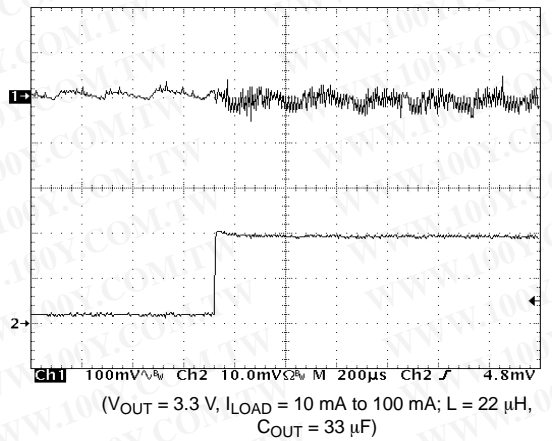
(V_{OUT} = 3.3 V, I_{LOAD} = 10 mA to 100 mA; L = 22 µH,
C_{OUT} = 33 µF)
Upper Trace: Output Voltage Ripple, 100 mV/Division
Lower Trace: Load Current, I_{LOAD}, 50 mA/Division

Figure 24. Load Transient Response for V_{IN} = 1.8 V

(V_{OUT} = 3.3 V, I_{LOAD} = 10 mA to 100 mA; L = 22 µH,
C_{OUT} = 33 µF)
Upper Trace: Output Voltage Ripple, 100 mV/Division
Lower Trace: Load Current, I_{LOAD}, 50 mA/Division

Figure 25. Load Transient Response for V_{IN} = 2.4 V

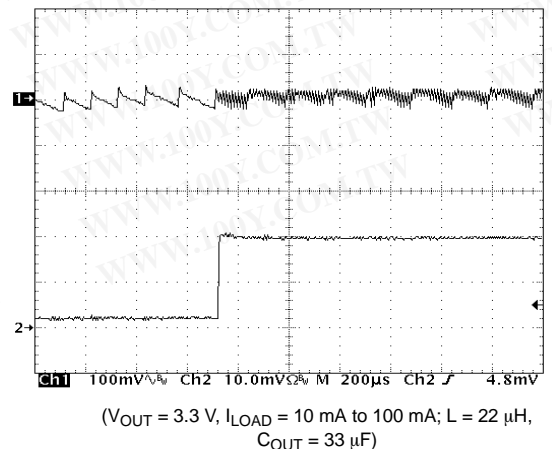(V_{OUT} = 3.3 V, I_{LOAD} = 10 mA to 100 mA; L = 22 µH,
C_{OUT} = 33 µF)
Upper Trace: Output Voltage Ripple, 100 mV/Division
Lower Trace: Load Current, I_{LOAD}, 50 mA/Division

Figure 26. Load Transient Response for V_{IN} = 3.3 V

DETAILED OPERATION DESCRIPTIONS

NCP1410 is a monolithic micropower high frequency step–up voltage switching converter IC specially designed for battery operated hand–held electronic products up to 250 mA loading. It integrates Synchronous Rectifier for improving efficiency as well as eliminating the external Schottky Diode. High switching frequency (up to 600 kHz) allows low profile inductor and output capacitor being used. Low–Battery Detector, Logic–Controlled Shutdown and Cycle–by–Cycle Current Limit provide value–added features for various battery–operated application. With all these functions ON, the quiescent supply current is only 9.0 μA typical. This device is available in a compact Micro8 package.

PFM Regulation Scheme

From the simplified Functional Diagram (Figure 2), the output voltage is divided down and fed back to pin 1 (FB). This voltage goes to the non–inverting input of the PFM comparator whereas the comparator's inverting input is connected to REF. A switching cycle is initiated by the falling edge of the comparator, at the moment, the main switch (M1) is turned ON. After the maximum ON–time (typical 1.4 μS) elapses or the current limit is reached, M1 is turned OFF, and the synchronous switch (M2) is turned ON. The M1 OFF time is not less than the minimum OFF–time (typical 0.31 μS), this is to ensure energy transfer from the inductor to the output capacitor. If the regulator is operating at continuous conduction mode (CCM), M2 is turned OFF just before M1 is supposed to be ON again. If the regulator is operating at discontinuous conduction mode (DCM), which means the coil current will decrease to zero before the next cycle, M1 is turned OFF as the coil current is almost reaching zero. The comparator (ZLC) with fixed offset is dedicated to sense the voltage drop across M2 as it is conducting, when the voltage drop is below the offset, the ZLC comparator output goes HIGH, and M2 is turned OFF. Negative feedback of closed loop operation regulates voltage at pin 1 (FB) equal to the internal voltage reference (1.190 V).

Synchronous Rectification

Synchronous Rectifier is used to replace Schottky Diode for eliminating the conduction loss contributed by forward voltage of the latter. Synchronous Rectifier is normally realized by powerFET with gate control circuitry which, however, involved relative complicated timing concerns.

As main switch M1 is being turned OFF, if the synchronous switch M2 is just turned ON with M1 not being completed turned OFF, current will be shunt from the output bulk capacitor through M2 and M1 to ground. This power loss lowers overall efficiency. So a certain amount of dead time is introduced to make sure M1 is completely OFF before M2 is being turned ON.

When the main regulator is operating in CCM, as M2 is being turned OFF, and M1 is just turned ON with M2 not being completed OFF, the above mentioned situation will occur. So dead time is introduced to make sure M2 is completed OFF before M1 is being turned ON.

When the regulator is operating in DCM, as coil current is dropped to zero, M2 is supposed to be OFF. Fail to do so, reverse current will flow from the output bulk capacitor through M2 and then the inductor to the battery input. It causes damage to the battery. So the ZLC comparator comes with fixed offset voltage to switch M2 OFF before any reverse current builds up. However, if M2 is switch OFF too early, large residue coil current flows through the body diode of M2 and increases conduction loss. Therefore, determination on the offset voltage is essential for optimum performance.

With the implementation of synchronous rectification, efficiency can be as high as 92%. For single cell input voltage, use an external Schottky diode such as MBR0520 connected from pin 7 to pin 8 to ensure start–up.

Cycle–by–Cycle Current Limit

From Figure 2, SENSEFET is applied to sample the coil current as M1 is ON. With that sample current flowing through a sense resistor, sense–voltage is developed. Threshold detector (ILIM) detects whether the sense–voltage is higher than preset level. If it happens, detector output signifies the CONTROL LOGIC to switch OFF M1, and M1 can only be switched ON as next cycle starts after the minimum OFF–time (typical 0.31 μS). With properly sizing of SENSEFET and sense resistor, the peak coil current limit is set at 1.0 A typically.

Voltage Reference

The voltage at REF is set typically at +1.190 V. It can output up to 2.5 mA with load regulation ±1.5%, at V_{OUT} equal to 3.3 V. If V_{OUT} is increased, the REF load capability can also be increased. A bypass capacitor of 0.15 μF is required for proper operation when REF is not loaded. If REF is loaded, 1.0 μF capacitor at REF is needed.

Shutdown

The IC is shutdown when the voltage at pin 5 ($\overline{SHDN}$) is pulled lower than 0.3 V. During shutdown, M1 and M2 are both switched OFF, however, the body diode of M2 allows current flow from battery to the output, the IC internal circuit will consume less than 0.05 μA current typically. If the pin 5 voltage is pull higher than 0.6 V, for example, by a resistor connected to VIN, the IC is enabled, and the internal circuit will only consume 9.0 μA current typically from the OUT pin. Refer to Figure 2, the product of R_{SHDN} and C_{SHDN} must be larger than (500 k · 56 nF, i.e. 28 msec). This is to provide reset pulse for startup as battery is plugged in.

Low–Battery Detection

A comparator with 30 mV hysteresis is applied to perform the low–battery detection function. When pin 2 (LBI) is at a voltage, which can be defined by a resistor divider from the battery voltage, lower than the internal reference voltage, 1.190 V, the comparator output will cause a 50 Ohm low side switch to be turned ON. It will pull down the voltage at pin 3 (LBO) which has a hundreds kilo–Ohm of pull–high resistance. If the pin 2 voltage is higher than 1.190 V + 30 mV, the comparator output will cause the 50 Ohm low side switch to be turned OFF, pin 3 will become high impedance, and its voltage will be pulled high by the external resistor.

APPLICATIONS INFORMATION

Output Voltage Setting

The output voltage of the converter is determined by the external feedback network comprised of R_{FB1} and R_{FB2} and the relationship is given by:

$$V_{OUT} = 1.190 \text{ V} \times \left(1 + \frac{R_{FB1}}{R_{FB2}}\right)$$

where R_{F2} and R_{F1} are the upper and lower feedback resistors respectively.

Low Battery Detect Level Setting

The Low Battery Detect Voltage of the converter is determined by the external divider network comprised of R_{LB1} and R_{LB2} and the relationship is given by:

$$V_{LB} = 1.190 \text{ V} \times \left(1 + \frac{R_{LB1}}{R_{LB2}}\right)$$

where R_{LB1} and R_{LB2} are the upper and lower divider resistors respectively.

Inductor Selection

The NCP1410 is tested to produce optimum performance with a 22 μH inductor at $V_{IN} = 3$ V, $V_{OUT} = 3.3$ V supplying output current up to 250 mA. For other input/output requirements, inductance in the range 10 μH to 47 μH can be used according to end application specifications. Selecting an inductor is a compromise between output current capability and tolerable output voltage ripple. Of course, the first thing we need to obey is to keep the peak inductor current below its saturation limit at maximum current and the I_{LIM} of the device. In NCP1410, I_{LIM} is set at 1 A. As a rule of thumb, low inductance values supply higher output current, but also increase the ripple at output and reducing efficiency, on the other hand, high inductance values can improve output ripple and efficiency, however it also limit the output current capability at the same time. One other parameter of the inductor is its DC resistance, this resistance can introduce unwanted power loss and hence reduce overall efficiency, the basic rule is selecting an inductor with lowest DC resistance within the board space limitation of the end application.

Capacitors Selection

In all switching mode boost converter applications, both the input and output terminals sees pulsating voltage/current waveforms. The currents flowing into and out of the capacitors multiplying with the Equivalent Series Resistance (ESR) of the capacitor producing ripple voltage at the terminals. During the syn–rect switch off cycle, the charges stored in the output capacitor is used to sustain the output load current. Load current at this period and the ESR combined and reflected as ripple at the output terminals. For all cases, the lower the capacitor ESR, the lower the ripple voltage at output. As a general guide line, low ESR capacitors should be used. Ceramic capacitors have the lowest ESR, but low ESR tantalum capacitors can also be used as a cost effective substitute.

Optional Startup Schottky Diode for Low Battery Voltage

In general operation, no external Schottky diode is required, however, in case you are intended to operate the device close to 1 V level, a Schottky diode connected between the LX and OUT pins as shown in Figure 27 can help during startup of the converter. The effect of the additional Schottky was shown in Figure 8.
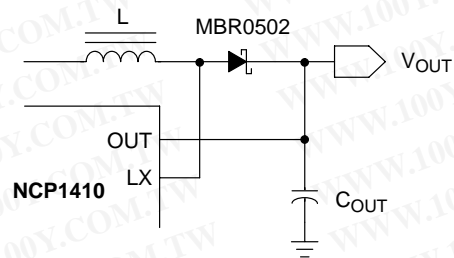

Figure 27. Schottky Device Between LX and OUT Pins

PCB Layout Recommendations

Good PCB layout plays an important role in switching mode power conversion. Careful PCB layout can help to minimize ground bounce, EMI noise and unwanted feedback that can affect the performance of the converter. Hints in the following paragraphs, can be used as guidelines in most situations.

Grounding

Star–ground connection should be used to connect the output power return ground, the input power return ground and the device power ground together at one point. All high current running paths must be thick enough for current flowing through and producing insignificant voltage drop along the path. Feedback signal path must be separated with the main current path and sensing directly at the anode of the output capacitor.

NCP1410

Components Placement

Power components, i.e. input capacitor, inductor and output capacitor, must be placed as close together as possible. All connecting traces must be short, direct and thick. High current flowing and switching paths must be kept away from the feedback (FB, pin 1) terminal to avoid unwanted injection of noise into the feedback path.

Feedback Network

Feedback of the output voltage must be a separate trace detached from the power path. External feedback network must be placed very close to the feedback (FB, pin 1) pin and sensing the output voltage directly at the anode of the output capacitor.

TYPICAL APPLICATION CIRCUIT
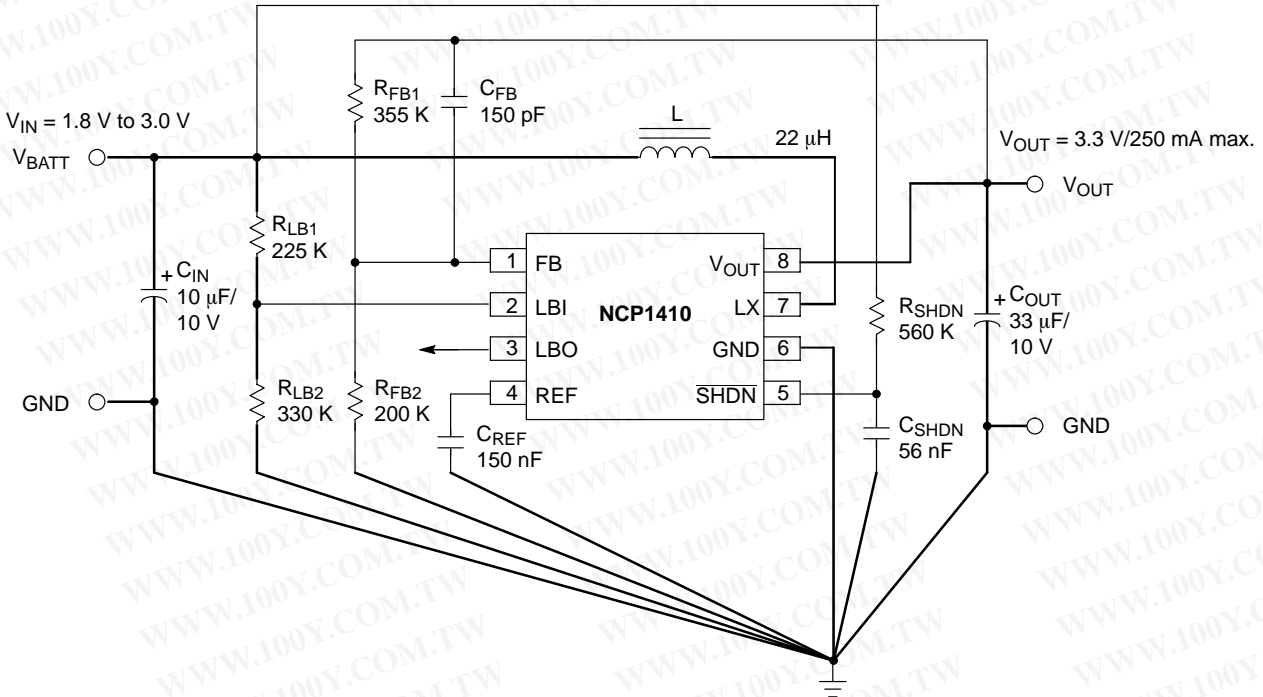
Figure 28. Typical Application Schematic for 2 Alkaline Cells Supply

GENERAL DESIGN PROCEDURES

Switching mode converter design is considered as black magic to most engineers, some complicate empirical formulae are available for reference usage. Those formulae are derived form the assumption that the key components, i.e. power inductor and capacitors are available with no tolerance. Practically, its not true, the result is not a matter of how accurate the equations you are using to calculate the component values, the outcome is still somehow away from the optimum point. In below a simple method base on the most basic first order equations to estimate the inductor and capacitor values for NCP1410 operate in Continuous Conduction Mode is introduced. The component value set can be used as a starting point to fine tune the circuit operation. By all means, detail bench testing is needed to get the best performance out of the circuit.

Design Parameters:

V_{IN} = 1.8 V to 3.0 V, Typical 2.4 V
V_{OUT} = 3.3 V
I_{OUT} = 200 mA (250 mA max)
V_{LB} = 2.0 V
$V_{OUT-RIPPLE}$ = 40 mV_{P-P} at I_{OUT} = 250 mA

Calculate the feedback network:
Select R_{FB2} = 200 K

$$R_{FB1} = R_{FB2}\left(\frac{V_{OUT}}{V_{REF}} - 1\right)$$

$$R_{FB1} = 200\ K\left(\frac{3.3\ V}{1.19\ V} - 1\right) = 355\ K$$

Calculate the Low Battery Detect divider:
V_{LB} = 2.0 V
Select R_{LB2} = 330 K

$$R_{LB1} = R_{LB2}\left(\frac{V_{LB}}{V_{REF}} - 1\right)$$

$$R_{LB1} = 330\ K\left(\frac{2.0\ V}{1.19\ V} - 1\right) = 225\ K$$

Determine the Steady State Duty Ratio, D for typical V_{IN}, operation will be optimized around this point:

$$\frac{V_{OUT}}{V_{IN}} = \frac{1}{1-D}$$

$$D = 1 - \frac{V_{IN}}{V_{OUT}} = 1 - \frac{2.4\ V}{3.3\ V} = 0.273$$

Determine the average inductor current, I_{LAVG} at maximum I_{OUT}:

$$I_{LAVG} = \frac{I_{OUT}}{1-D} = \frac{250\ mA}{1-0.273} = 344\ mA$$

Determine the peak inductor ripple current, $I_{RIPPLE-P}$ and calculate the inductor value:

Assume $I_{RIPPLE-P}$ is 20% of I_{LAVG}, the inductance of the power inductor can be calculated as in below:

$$I_{RIPPLE-P} = 0.20 \times 344\ mA = 68.8\ mA$$

$$L = \frac{V_{IN} \times t_{ON}}{2\ I_{RIPPLE-P}} = \frac{2.4\ V \times 1.4\ \mu S}{2(68.8\ mA)} = 24.4\ \mu H$$

Standard value of 22 μH is selected for initial trial.

Determine the output voltage ripple, $V_{OUT-RIPPLE}$ and calculate the output capacitor value:
$V_{OUT-RIPPLE}$ = 40 mV_{P-P} at I_{OUT} = 250 mA

$$C_{OUT} > \frac{I_{OUT} \times t_{ON}}{V_{OUT-RIPPLE} - I_{OUT} \times ESR_{COUT}}$$

where t_{ON} = 1.4 μS and ESR_{COUT} = 0.1 Ω,

$$C_{OUT} > \frac{250\ mA \times 1.4\ \mu S}{40\ mV - 250\ mA \times 0.1\ \Omega} = 23.33\ \mu F$$

From above calculation, you need at least 23.33 μF in order to achieve the specified ripple level at conditions stated. Practically, a one level larger capacitor will be used to accommodate factors not take into account in the calculation, therefore a capacitor value of 33 μF is selected.
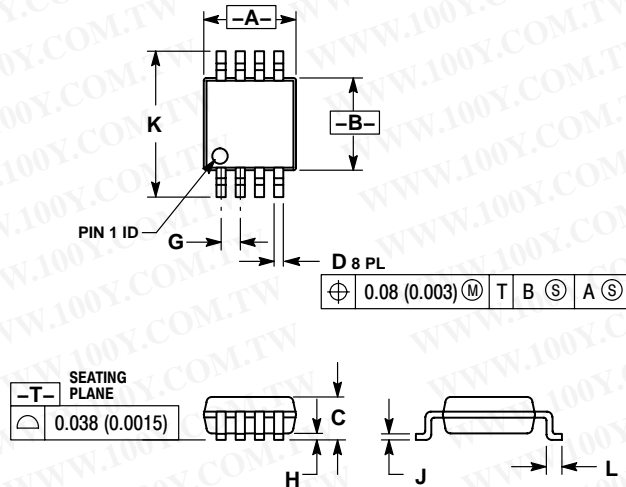
NCP1410

PACKAGE DIMENSIONS

Micro8
DM SUFFIX
CASE 846A−02
ISSUE F

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. 846A−01 OBSOLETE, NEW STANDARD 846A−02.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	---	1.10	---	0.043
D	0.25	0.40	0.010	0.016
G	0.65 BSC		0.026 BSC	
H	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

SOLDERING FOOTPRINT*

SCALE 8:1 $\left(\frac{mm}{inches}\right)$
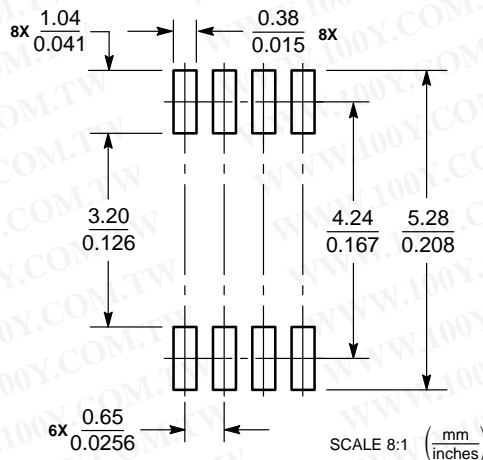
*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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